

L Number	Hits	Search Text	DB	Time stamp
13	44	nanostructure and ( cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/02 14:41
18	22	nanocomposite and semiconducting	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/02 15:34
19	0	(nanocomposite and semiconducting) and cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/02 15:34
20	58	(nanocomposite or nanostructure or (nanocomposite near material)) and cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/02 15:35
-	1011	(174/36).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 13:49
-	24	(high adj frequency) near (power adj cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 10:29
-	730	(high adj frequency) near cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 10:31
-	0	"plurality of insulated conductors"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 13:59
-	8	vinyl near conductors	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 14:01
-	44	vinyl and (multiconductor adj cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 14:08
-	11393	vinyl and cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 14:06
-	1691	(hollow or (empty adj center))and (vinyl and cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 14:07
-	46	(counter adj (electromagnetic adj force))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 14:10
-	2	(electromagnetic adj force) and ((hollow or (empty adj center))and (vinyl and cable))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 14:10

-	5	(electromagnetic adj force) and (vinyl and cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 14:15
-	14	nanocomposite and cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 17:26
-	22	nanocomposite and semiconducting	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/02 15:34
-	18	nano and semiconducting and cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 17:33
-	19	nano and (power adj cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 17:39
-	0	(inorganic adj compound) and micron and semiconducting and cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 18:04
-	4	(inorganic adj compound) and semiconducting and cable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 19:22
-	39	(semiconducting adj layers) and (power adj cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 19:25
-	2	nanosstructure and ((semiconducting adj layers) and (power adj cable))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 19:28
-	14	nanosstructure and (power adj cable)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 19:31
-	30	(nanosstructure and ( cable)) not (nanosstructure and (power adj cable))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/28 19:31